PATENT

Practitioner's Docket No.: 811 107

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of:

Makoto IWAI, Katsuhiro IMAI and Minoru IMAEDA

Ser. No.: 10/594,846

Group Art Unit: 1792

Filed: November 8, 2006

Examiner: Felisa Carla Hiteshew

Confirmation No.: 3664

GALLIUM NITRIDE SINGLE CRYSTAL GROWING METHOD AND

GALLIUM NITRIDE SINGLE CRYSTAL

Mail Stop Amendment Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

CERTIFICATION OF EFS TRANSMISSION

I hereby certify that this paper is being transmitted via EFS to the Payent and Trademark Office on June 11, 2008.

REQUEST FOR RECONSIDERATION

Sir:

In response to the Office Action mailed April 16, 2008, Applicants respectfully request reconsideration and withdrawal of the rejections of record based on the following arguments.

Claims 1-7 are pending herein.

Examiner Hiteshew is thanked for courtesies extended to Applicants' representatives during a telephonic interview on May 7, 2008. The substance of that interview has been incorporated into the following remarks.

Claims 1-7 were rejected under §103(a) over Kawamura. This rejection 1. is respectfully traversed.